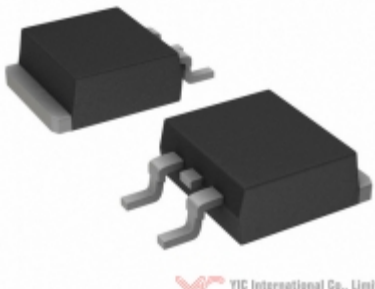











	<h2 style="color: orange;">FQB19N20CTM</h2>
 <p>Image may be representation. See specs for product details.</p>	Hersteller-Teilenummer: FQB19N20CTM
	Hersteller / Marke: Fairchild/ON Semiconductor
	Teil der Beschreibung: MOSFET N-CH 200V 19A D2PAK
	Datenblätter:  FQB19N20CTM.pdf
	RoHs Status: Bleifrei / RoHS-konform
	Lagerzustand: New original, 1007 pcs Stock Available.
Liefern von: Hong Kong	
Versandweg: DHL/Fedex/TNT/UPS/EMS	

Spezifikationen

Teilenummer	FQB19N20CTM
Hersteller	Fairchild/ON Semiconductor
Beschreibung	MOSFET N-CH 200V 19A D2PAK
Kategorie	Diskrete Halbleiterprodukte > Transistoren-FETs,
Teilstatus	1007 pcs Stock
Serie	QFET®
Technologie	MOSFET (Metal Oxide)
Betriebstemperatur	-55°C ~ 150°C (TJ)
Befestigungsart	Surface Mount
Verpackung / Gehäuse	TO-263-3, D ² Pak (2 Leads + Tab), TO-263AB
Supplier Device-Gehäuse	D ² PAK (TO-263AB)
Verlustleistung (max)	3.13W (Ta), 139W (Tc)
Typ FET	N-Channel
FET-Merkmal	-
Drain-Source-Spannung (Vdss)	200V
Strom - Ununterbrochener Abfluss (Id) bei 25 ° C	19A (Tc)
Rds On (Max) @ Id, Vgs	170 mOhm @ 9.5A, 10V
VGS (th) (Max) @ Id	4V @ 250µA
Gate Charge (Qg) (Max) @ Vgs	53nC @ 10V
Eingabekapazität (Ciss) (Max) @ Vds	1080pF @ 25V
Antriebsspannung (Max Rds On, Min Rds On)	10V
Vgs (Max)	±30V
Verpackung	Original-Reel®












































FQB19N20CTM ist neu im Original, Suche FQB19N20CTM Datenblätter, PDF, Inventar bei Y-IC.com Online, Bestellen Sie FQB19N20CTM Fairchild/ON Semiconductor mit Garantie und Vertrauen. Anfrage FQB19N20CTM: Info@Y-IC.com

Sie können auch interessiert sein:

 <p>FQB19N10TM Fairchild/ON Semiconductor MOSFET N-CH 100V 19A D2PAK</p>	 <p>FQB19N20 F FQB19N20 F</p>	 <p>FQB19N20CTM AMI Semiconductor / ON Semiconductor MOSFET N-CH 200V 19A D2PAK</p>	 <p>FQB19N20C F FQB19N20C F</p>
 <p>FQB19N20LTM Fairchild/ON Semiconductor MOSFET N-CH 200V 21A D2PAK</p>	 <p>FQB19N20LTM AMI Semiconductor / ON Semiconductor MOSFET N-CH 200V 21A D2PAK</p>	 <p>FQB19N10LTM AMI Semiconductor / ON Semiconductor MOSFET N-CH 100V 19A D2PAK</p>	 <p>FQB19N10TM AMI Semiconductor / ON Semiconductor MOSFET N-CH 100V 19A D2PAK</p>

heiße Teile

Mehr

 FQB12P20	 FQB12P20TM	 FQB12P20TM	D FQB13N06L	 FQB13N10
 FQB13N10L	 FQB13N50	D FQB13N50CTM	 FQB13N50CTM	 FQB140N03L
 FQB14N30TM	 FQB14N30TM	 FQB16N25TM	 FQB16N25TM	 FQB17P06
D FQB17P10	 FQB17P10TM	 FQB17P10TM	 FQB19N10L	 FQB19N10LTM
 FQB19N10LTM	 FQB19N10TM	 FQB19N10TM	 FQB19N20	 FQB19N20C
 FQB19N20CTM	 FQB19N20L	D FQB19N20LTM	 FQB19N20LTM	 FQB19N20TM
 FQB19N20TM	D FQB1N60TM	 FQB1N60TM	 FQB20N06L	 FQB20N60FTM
 FQB20N60TM	 FQB22P10	 FQB22P10TM	 FQB22P10TM	 FQB22P10TM_F085
 FQB24N08TM	 FQB24N08TM	 FQB25N33	D FQB25N33TM	 FQB25N33TM
 FQB25N33TM_F085	 FQB27N25TM	 FQB27P06	 FQB27P06TM	 FQB27P06TM

Contact us: Info@Y-IC.com

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